FEB 1 0 2006 By Pater Shunpei Y

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

hore Patent Application of:)	Group Art Unit: 2826
Shunpei YAMAZAKI et al.)	Examiner: Fetsum Abraham
Serial No. 10/712,062)	CERTIFICATE OF MAILING I hereby certify that this correspondence
Filed: November 14, 2003)	being deposited with the United States Pos

For: SEMICONDUCTOR DEVICE AND

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Commissioner for Patents, P.O. Box 1450,

METHOD OF FABRICATING SAME) Alexandria, VA 22313-1450, on 2.8.06

INFORMATION DISCLOSURE STATEMENT

Honorable Commissioner of Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

In accordance with the provisions of 37 C.F.R. 1.56 and 37 C.F.R. 1.97-1.99, Applicant submits herewith a Form PTO-1449 listing information known to Applicant and requests that this information be made of record in the above identified application. Copies are submitted herewith in accordance with 37 C.F.R. 1.98(a).

Copies of U.S. patents and U.S. publications are not enclosed in accordance with the Notice published in the Official Gazette on August 5, 2003 entitled *Information Disclosure Statements May Be Filed Without Copies of U.S. Patents and Published Applications in Patent Applications filed after June 30, 2003*, which waives the requirement under 37 CFR 1.98(a)(2)(i) for submitting a copy of each cited U.S. patent and each U.S. publication.

This Information Disclosure Statement is being submitted with an RCE. Therefore, no fee is required.

Respectfully submitted,

Eric J. Robinson

Reg. No. 38,285

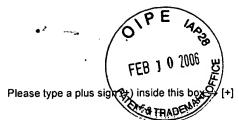
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PTO/SB/08A (08-00)

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Substitut	te for form 1449A/PT0)		Complete if Known		
INEO	RMATION E	וופרו	OSLIDE	Application Number	10/712,062	
				Filing Date	November 14, 2003	
STATEMENT BY APPLICANT				First Named Inventor	Shunpei YAMAZAKI et al.	
	(use as many sheets	as nece	ssary)	Group Art Unit	2826	
				Examiner Name	Fetsum Abraham	
Sheet	1	of	1	Attorney Docket Number 0756-7218		

Sheet	1	of 1				Attorney Docket Number			0756-7218		
						U.S. PATENT DOCUM	IEN'	rs	· · · ·		
Examiner Initials	No. ¹ Number Kind Code ²		e ²			Date of Publication of Cited Document MM-DD-YYYY		Relevant Passages or	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
		F 060	262	(if known)		amazaki et al.	·	02/09/1999	<u> </u>		
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^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Attorney Docket No. 0756-7218



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:)	Group Art Unit: 2826
Shunpei YAMAZAKI et al.)	Examiner: Fetsum Abraham
Serial No. 10/712,062)	CERTIFICATE OF MAILING I hereby certify that this correspondence is
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For: SEMICONDUCTOR DEVICE AND)	Mail in an envelope addressed to:
METHOD OF FABRICATING SAME)	Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on 2-8-06.

CORRECTION TO PREVIOUSLY SUBMITTED INFORMATION DISCLOSURE STATEMENT

Honorable Commissioner of Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

It has come to applicant's attention that an Information Disclosure Statement previously submitted included inadvertent typographical errors or incomplete information.

Specifically, the Information Disclosure Statement filed November 14, 2003 included the following inaccuracies:

- 1) U.S. Patent 4,330,363 was incorrectly listed with the inventor as Biefesen et al. The correct inventor should be Biegesen et al.;
- 2) U.S. Patent 4,996,077 was incorrectly listed with the inventor as Mosiehi et al. The correct inventor should be Moslehi et al.
- 3) U.S. Patent No. 5,089,441 is incorrected lised with the inventor as Mosiehi et al. The correct inventor should be Moslehi et al.
- 4) EP 0 178 447 was incorrectly listed with a publication date of 10/09/84. The correct publication date is 04/23/1986.
- 5) The article to Kruper et al. did not include the volume and number. The corrected citation should read: Kuper et al., "Effects of Fluorine Implantation on the

Kinetics of Dry Oxidation of Silicon," <u>Volume 60, No. 3,</u> August 1, 1986, pp. 985-990, J. Applied Physics.

- 6) The article to Nemanich et al. incorrectly lists the volume. The correct volume number is 23.
- 7) The article to Wolf et al. did not include the volume. The corrected citation should read: Wolf et al., "Thermal Oxidation of Single Crystal Silicon," <u>Volume 1, 1986</u>, pp. 207-211, Silicon Processing for the VLSI Era.
- 8) The article to Dvurechenskii et al. did not include the volume. The corrected citation should read: Dvurechenskii et al., "Transport Phenomena in Amorphous Silicon Doped by Ion Implantation of 3d Metals," <u>Volume 95</u>, 1986, pp. 635-640, Akademikian Lavrentev Prospekt 13, 630090 Novosibirsk 90, USSR.
- 9) The article to Hayzelden et al. incorrectly lists the date as May 15, 1993. The correct date is June 1, 1993.
- 10) Page 5 and 10 of the Information Disclosure Statement have been initialed by the Examiner and dated "8/30/01." The subject application was filed on November 14, 2003, and therefore the date of review of incorrect. Copies are enclosed.

The above inaccuracies are corrected on the 1449 Form attached hereto. This Correction to Previously Submitted Information Disclosure Statements is being submitted herewith with an Information Disclosure Statement, RCE, and requisite fee. The Examiner is requested to initial the attached PTO Form 1449 evidencing consideration of the above references and line through these references on the previously submitted Information Disclosure Statements to ensure that the correct information is printed correctly on any issued patent.

Respectfully submitted,

Eric J. Robinson

Reg. No. 38,285

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Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number. Complete if Known Substitute for form 1449A/PTO 10/712,062 **Application Number** INFORMATION DISCLOSURE November 14, 2003 Filing Date STATEMENT BY APPLICANT Shunpei YAMAZAKI et al. First Named Inventor (use as many sheets as necessary) 2826 **Group Art Unit** Fetsum Abraham **Examiner Name Attorney Docket Number** Sheet 1 0756-7218

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Examiner Signature			-			Date	idered			
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^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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INFO	RMATION I)ICC	TEPSTIDE	Application Number	Based on 10/214,691			
INFORMATION DISCESSURE STATEMENT BY APPLICANT (use as many sheets as necessary)				Filing Date	August 9, 2002			
				First Named Inventor	Shunpei YAMAZAKI, et al.			
				Group Art Unit	2826			
				Examiner Name	Fetsum Abraham			
Sheet	5	of	12	Attorney Docket Number	0756-7218			

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Examiner Cite No.1		U.S. Patent Document		Name of Patentee or Applicant of Cited	Date of Publication of Cited Document	Pages, Cohumns, Lines, Where Relevant Passages or Relevant Figures Appear			
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Sheet

Examiner Signature 10

Complete if Known					
Application Number	Based on 10/214,691				
Filing Date	August 9, 2002				
First Named Inventor	Shunpei YAMAZAKI, et al.				
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Examiner Name	Fetsum Abraham				
Attorney Docket Number	0756-7218				

				U.S. PATENT DOCUMEN	TS	
Examiner Initials*	Cite No.1	U.S. Patent I	Kind Code ³	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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Date Considered